

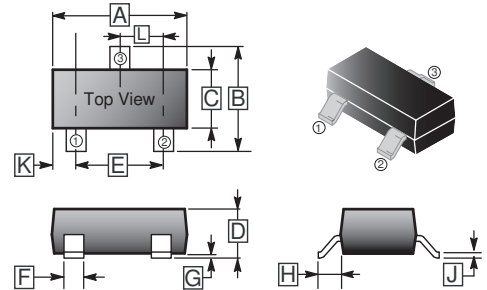
RoHS Compliant Product
 A suffix of "-C" specifies halogen & lead-free

DESCRIPTION

Designed to protect voltage sensitive electronic components from ESD and other transients. Excellent clamping capability, low leakage, low capacitance, and fast response time provide best in class protection on designs that are exposed to ESD.

The combination of small size, low capacitance, and high level of ESD protection makes them a flexible solution for applications such as HDMI, Display Port TM, and MDDI interfaces. It is designed to replace multi-layer varistors (MLV) in consumer equipments applications such as mobile phone, notebook, PAD, STB, LCD TV etc.

SOT-23

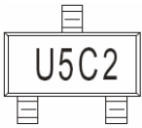


REF.	Millimeter		REF.	Millimeter	
	Min.	Max.		Min.	Max.
A	2.70	3.10	G	0	0.18
B	2.10	3.00	H	0	0.55 REF.
C	1.20	1.80	J	0.08	0.26
D	0.89	1.3	K	0	0.6 REF.
E	1.70	2.3	L	0	0.95 BSC.
F	0.30	0.50			

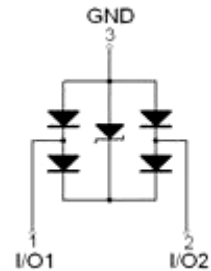
FEATURES

- Uni-Directional ESD Protection of Two Lines
- Low Capacitance
- Low Reverse Stand-off Voltage
- Low Reverse Clamping Voltage
- Low Leakage Current
- Fast Response Time
- JESD22-A114-B ESD Rating of Class 3B Per Human Body Model
- IEC 61000-4-2 Level 4 ESD Protection

MARKING



Top View



PACKAGE INFORMATION

Package	MPQ	Leader Size
SOT-23	3K	7 inch

ORDER INFORMATION

Part Number	Type
SZMDU5C2	Lead (Pb)-free
SZMDU5C2-C	Lead (Pb)-free and Halogen-free

MAXIMUM RATINGS (T_A=25°C unless otherwise noted)

Parameter	Symbol	Ratings	Unit
IEC61000-4-2 ESD Voltage ¹	V _{ESD}	Air Model	±15
		Contact Model	±15
		Per Human Body Model	±16
		Machine Model	±0.4
Peak Pulse Power ²	P _{PP}	87.5	W
Peak Pulse Current ²	I _{PP}	3.5	A
Lead Solder Temperature-Maximum (10 Second Duration)	T _L	260	°C
Junction and Storage Temperature Range	T _J , T _{STG}	150, -55~150	°C

ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Reverse Stand-off Voltage	V_{RWM}	-	-	5	V	
Breakdown Voltage	V_{BR}	6	-	-	V	$I_T=1\text{mA}$
Clamping Voltage ²	V_C	-	-	15	V	$I_{PP}=1\text{A}$
		-	-	25		$I_{PP}=3.5\text{A}$
Forward Voltage	V_F	0.4	-	1.4	V	$I_F=10\text{mA}$
Reverse Leakage Current	I_R	-	-	1	μA	$V_{RWM}=5\text{V}$
Junction Capacitance	C_J	-	0.8	-	pF	$V_R=0, f=1\text{MHz}$
		-	0.4	-		$V_R=0, f=1\text{MHz}, I/O \text{ to } I/O$

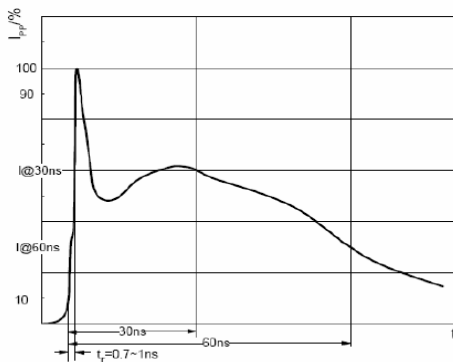
Notes:

1. Device stressed with ten non-repetitive ESD pulses, per channel (I/O to GND).
2. Non-repetitive current pulse 8/20 μs exponential decay waveform according to IEC61000-4-5.

ESD STANDARDS COMPLIANCE

IEC61000-4-2 Standard

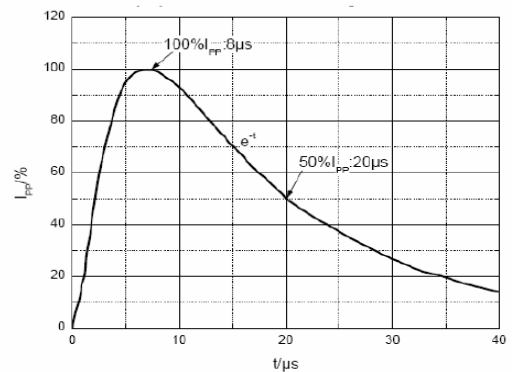
Contact Discharge		Air Discharge	
Level	Test Voltage kV	Level	Test Voltage kV
1	2	1	2
2	4	2	4
3	6	3	8
4	8	4	15



ESD pulse waveform according to IEC61000-4-2

JESD22-A114-B Standard

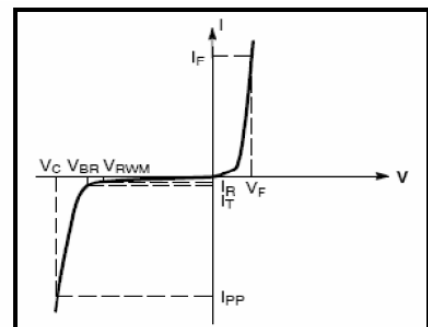
ESD Class	Human Body Discharge V
0	0~249
1A	250~499
1B	500~999
1C	1000~1999
2	2000~3999
3A	4000~7999
3B	8000~15999



8/20 μs pulse waveform according to IEC 61000-4-5

ELECTRICAL PARAMETER

Symbol	Parameter
V_C	Clamping Voltage @ I_{PP}
I_{PP}	Peak Pulse Current
V_{BR}	Breakdown Voltage @ I_T
I_T	Test Current
I_R	Reverse Leakage Current @ V_{RWM}
V_{RWM}	Reverse Standoff Voltage
V_F	Forward Voltage @ I_F
I_F	Forward Current

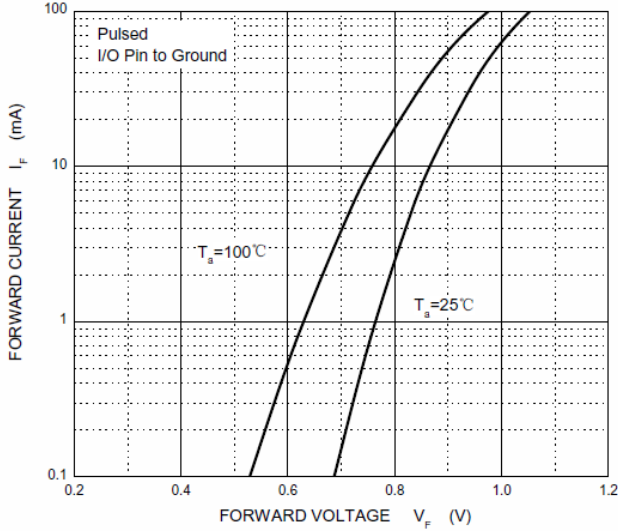


V-I characteristics for a uni-directional TVS

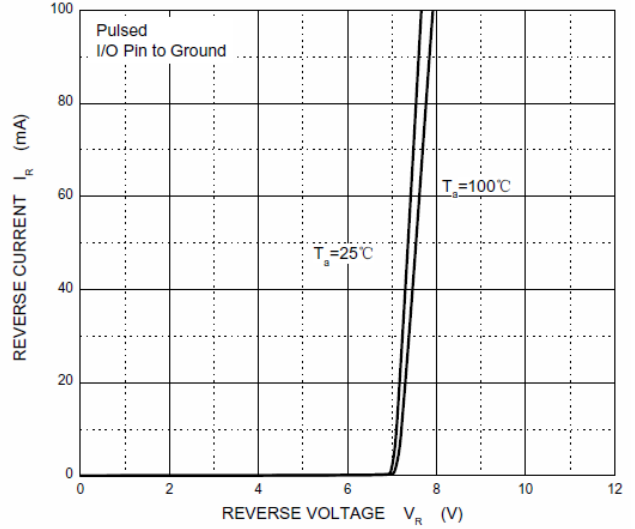
Any changes or specification will not be informed individually.

TYPICAL CHARACTERISTICS

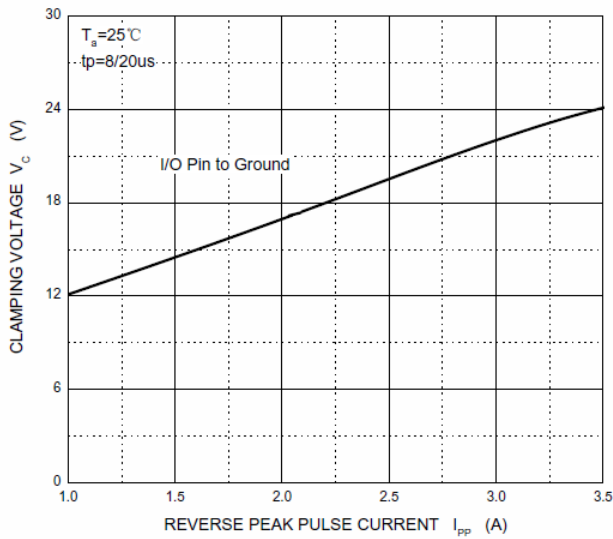
Forward Characteristics



Reverse Characteristics



V_C — I_{PP}



Capacitance Characteristics

